

Form 1449 (Modified) Information Disclosure Statement By Applicant (Use Several Sheets if Necessary)	Atty Docket No.	Application No.:
	UNTYP009	10/612,191
	Applicant:	
	Rinerson et al.	
	Filing Date	Group
	July 1, 2003	2818

U.S. Patent Documents

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub- class	Filing Date
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	B	5,920,500	1999-07-06	Tehrani et al.			
	C	6,545,891	2003-04-08	Tringali et al.			
	D	6,504,753	2003-01-07	Scheuerlein et al.			
	E	6,483,736	2002-11-19	Johnson et al.			
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	H	6,185,122	2001-02-06	Johnson et al.			
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	J	5,835,396	1998-11-10	Zhang			
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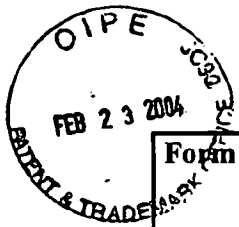
U.S. Published Patent Applications

Examiner Initial	No.	Document No.	Publication Date	Inventor
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Du	L	Beck, A. et al., "Reproducible switching effect in thin oxide films for memory applications", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000, 139-141.
	M	Rossel, C. et al., "Electrical current distribution across a metal-insulator-metal structure during bistable switching", Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.
hu	N	Watanabe, Y. et al., "Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped SrTiO ₃ single crystals", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.
Examiner	Tuan T. Nguyen	
Date Considered	10/1/04	

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



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Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
<i>Dr</i>	A	Liu, S.Q., et al., " <i>Electric-pulse-induced reversible resistance change effect in magnetoresistive films</i> ", Applied Physics Letters, Vol. 76, No. 19, 8 May 2000, 2749-2651.
<i>Dr</i>	B	Liu, S.Q., et al., " <i>A New Concept For Non-Volatile Memory: Electric-Pulse Induced Reversible Resistance Change Effect In Magnetoresistive Films</i> ", Space Vacuum Epitaxy Center, University of Huston, Huston TX, 7 Pages.
Examiner <i>Tuan T. Nguyen</i>	Date Considered <i>10/1/04</i>	

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